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Rohm Semiconductor RTQ025P02TR

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RTQ025P02

Transistor

DC-DC Converter (-20V, -2.5A) RTQ025P02

Features

- 1) Low On-resistance.(140m Ω at 2.5V)
- 2) High Power Package.
- 3) High speed switching.
- 4) Low voltage drive.(2.5V)

Applications

DC-DC converter

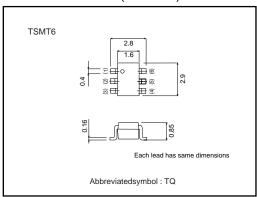
●Structure

Silicon P-channel **MOSFET**

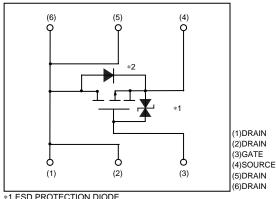
Packaging specifications

	Package	Taping
Туре	Code	TR
	Basic ordering unit (pieces)	3000
RTQ025P02		0

●External dimensions (Units : mm)



●Equivalent circuit



- *1 ESD PROTECTION DIODE
- *2 BODY DIODE



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● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Voss	-20	V
Gate-source voltage		Vgss	±12	V
Drain current	Continuous	lσ	±2.5	Α
	Pulsed	IDP	±10	A *1
Source current (Body diode)	Continuous	Is	-1	A
	Pulsed	Isp	-4	A *1
Total power dissipation		Po	1.25	W*2
Channel temperature		Tch	150	°C
Range of Storage temperature		Tstg	−55~+150	°C

^{*1} Pw≦10μs, Duty cycle≦1%

●Electrical characteristics (Ta=25°C)

IGSS V(BR)DSS IDSS VGS(th) RDS(on) Yfs *	- -20 - -0.7 - -	- - - - 72 80 140	±10 - -1 -2.0 100 110 190	μΑ V μΑ V mΩ	Vgs=±12V, Vds=0V Id=-1mA, Vgs=0V Vds=-20V, Vgs=0V Vds=-10V, Id=-1mA Id=-2.5A, Vgs=-4.5V Id=-2.5A, Vgs=-4V	
IDSS VGS(th) RDS(on)	- -0.7 - -	- - 72 80	-2.0 100 110	μΑ V mΩ mΩ	Vps=-20V, Vgs=0V Vps=-10V, Ip=-1mA Ip=-2.5A, Vgs=-4.5V	
VGS(th)	-0.7 - -	- 72 80	-2.0 100 110	V mΩ mΩ	V _{DS} =-10V, I _D =-1mA I _D =-2.5A, V _G S=-4.5V	
RDS(on)	-	72 80	100	mΩ mΩ	I _D =-2.5A, V _G s=-4.5V	
	-	80	110	mΩ		
	_				ID=-2.5A, VGS=-4V	
Yfs *		140	190			
Y _{fs} *	2.0			mΩ	ID=-1.2A, VGS=-2.5V	
	2.0	_	-	S	Vps=-10V, Ip=-1.2A	
Ciss	_	580	_	pF	V _{DS} =-10V,V _{GS} =0V f=1MHz	
Coss	_	110	-	pF		
Crss	_	80	_	pF		
td(on) *	-	12	_	ns	- I _D =−1.2A V _D D=−15V V _G S=−4.5V R ₁ =12.5Ω	
tr *	-	20	-	ns		
td(off) *	_	40	_	ns		
t f *	_	17	-	ns	$R_{GS}=10\Omega$	
Qg	_	6.4	-	nC		
Qgs	_	1.4	_	nC	VDD≒-15V VGS=-4.5V ID=-2.5A	
Qgd	-	1.9	-	nC		
	Coss Crss td(on) * tr * td(off) * Qg Qgs Qgd	Coss - Crss - td(on) * - tr * - td(off) * - Qg - Qgs - Qgd - Qgd - Coss	Coss - 110 Crss - 80 td(on)* - 12 tr - 20 td(off)* - 40 tr * - 17 Qg - 6.4 Qgs - 1.4	Coss - 110 - Crss - 80 - td(on)* - 12 - tr* - 20 - td(off)* - 40 - tr* - 17 - Qg - 6.4 - Qgs - 1.4 - Qgd - 1.9 -	Coss - 110 - pF Crss - 80 - pF td(on)* - 12 - ns tr* - 20 - ns td(off)* - 40 - ns tr* - 17 - ns Qg - 6.4 - nC Qgs - 1.4 - nC Qgd - 1.9 - nC	

Forward voltage VSD	-	_	-1.2	٧	Is=-1A, Vgs=0V
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^{*2} Mounted on a ceramic board

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Electrical characteristic curves

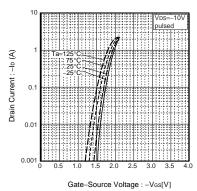
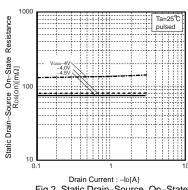


Fig.1 Typical Transfer Characteristics



Drain Current : -Ib[A]
Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

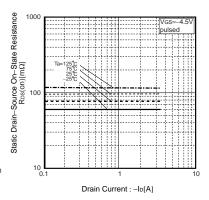


Fig.3 Static Drain-Source On-State Resistance vs.Drain Current

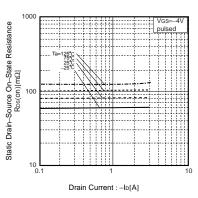


Fig.4 Static Drain-Source On-State Resistance vs. Drain-Current

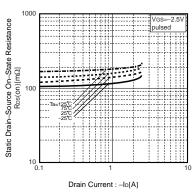


Fig.5 Static Drain-Source On-State Resistance vs. Drain-Current

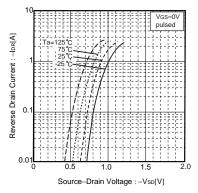


Fig.6 Reverse Drain Current vs. Source-Drain Voltage

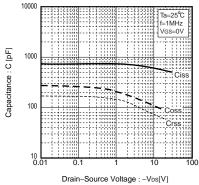


Fig.7 Typical Capactitance vs.Drain-Source Voltage

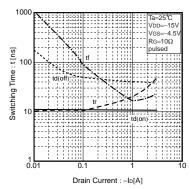


Fig.8 Switching Characteristics

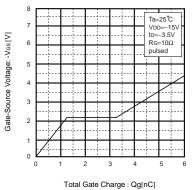


Fig.9 Dynamic Input Characteristics



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Measurement circuits

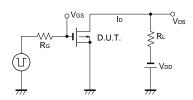


Fig.10 Switching Time Measurement Circuit

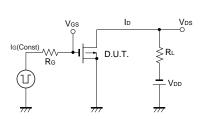


Fig.12 Gate Charge Measurement Circuit

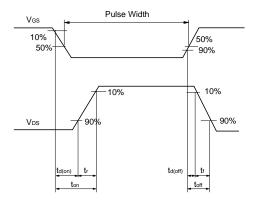


Fig.11 Switching Waveforms

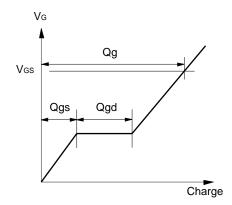


Fig.13 Gate Charge Waveforms

Distributor of Rohm Semiconductor: Excellent Integrated System Limited

Datasheet of RTQ025P02TR - MOSFET P-CH 20V 2.5A TSMT6

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Appendix

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